

	<h2 style="color: red;">FQP12N60</h2>	
	Hersteller-Teilenummer:	FQP12N60
	Hersteller / Marke:	AMI Semiconductor / ON Semiconductor
	Teil der Beschreibung:	MOSFET N-CH 600V 10.5A TO-220
	Datenblätter:	1.FQP12N60.pdf 2.FQP12N60.pdf
	RoHs Status:	Bleifrei / RoHS-konform
Lagerzustand:	New original, 29366 pcs Stock Available.	
Liefern von:	Hong Kong	
Versandweg:	DHL/Fedex/TNT/UPS/EMS	
Image may be representation. See specs for product details.		

Spezifikationen

Teilenummer	FQP12N60
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET N-CH 600V 10.5A TO-220
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	29366 pcs Stock
detaillierte Beschreibung	N-Channel 600V 10.5A (Tc) 180W (Tc) Through Hole
Serie	QFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Through Hole
Verpackung / Gehäuse	TO-220-3
Supplier Device-Gehäuse	TO-220-3
Verlustleistung (max)	180W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	600V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	10.5A (Tc)
Rds On (Max) @ Id, Vgs	700 mOhm @ 5.3A, 10V
VGS (th) (Max) @ Id	5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	54nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	1900pF @ 25V
Antriebsspannung (Max Rds On, Min Rds On)	10V
Vgs (Max)	±30V
Verpackung	Tube
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)

FQP12N60 ist neu im Original, Suche FQP12N60 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FQP12N60 AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage FQP12N60: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>FQP12N40 FAIRCHILD FQP12N40 FAIRCHILD</p>	 <p>FQP12N60 Fairchild/ON Semiconductor MOSFET N-CH 600V 10.5A TO-220</p>	 <p>FQP12P10 AMI Semiconductor / ON Semiconductor MOSFET P-CH 100V 11.5A TO-220</p>	 <p>FQP12N50 FAIRCHILD FAIRCHILD TO-220</p>
 <p>FQP12N20 FSC FQP12N20 FSC</p>	 <p>FQP11P06 Fairchild/ON Semiconductor MOSFET P-CH 60V 11.4A TO-220</p>	 <p>FQP12N65C VB FQP12N65C VB</p>	 <p>FQP12N60C AMI Semiconductor / ON Semiconductor MOSFET N-CH 600V 12A TO-220</p>

heiße Teile

Mehr

FQP10N20	FQP10N20	FQP10N20C	D FQP10N20C	FQP10N20L
FQP10N60B	FQP10N60C	D FQP10N60C	FQP10N60CF	FQP10N60C_07
FQP10N65	FQP10N65C	FQP10N80	FQP11N40C	FQP11N40C
D FQP11N50CF	FQP11N50CF	FQP11N60	FQP11N60C	FQP11N65C
FQP11P06	FQP11P06	FQP12N20	FQP12N60	FQP12N60C
FQP12N60C	FQP12N65C	D FQP12P10	FQP12P10	FQP12P20
FQP12P20	D FQP13N06	FQP13N06	FQP13N06L	FQP13N06L
FQP13N10	FQP13N10	FQP13N10L	FQP13N10L	FQP13N50
FQP13N50	FQP13N50C	FQP13N50C	D FQP13N60C	FQP140N03
FQP140N03L	FQP14N15	FQP14N15	FQP14N30	FQP14N30

Contact us:Info@Y-IC.com

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